

Silicon ESD Protection Devices

NEW

Silicon ESD (SESD) devices help protect electronic circuits against damage from electrostatic discharge (ESD) events. The 0201-sized SESD device's miniature footprint - measuring 0.6mm x 0.3mm x 0.3mm - is approximately 70 percent smaller than prior-generation devices, offering designers flexibility in space-constrained applications.

The SESD0201C-006-058 device is a bi-directional and ultra-low capacitance 0.6 picofarad (pF) device that is suitable for helping to protect very-high-speed data lines, such as USB and HDMI, or low-voltage antenna ports. The device's ultra-low capacitance, low insertion loss (<0.5dB up to 3GHz), and high linearity of capacitance versus frequency helps minimize signal degradation.

The SESD0201C-120-058 device is a higher-capacitance (12pF) bi-directional device that can be used for low-speed generic interfaces such as keypads, power buttons, speakers, and microphone ports in portable electronics. Both SESD0201C-006-058 and SESD0201C-120-058 devices offer 8kV contact and 15kV air discharge protection per the IEC61000-4-2, level 4 standard.

Also included in the product line is the SESD0402S-005-054 device, an ultra-low-capacitance SOD-923 (0402-size package) uni-directional device with 0.5pF typical capacitance. This device offers a 10kV contact discharge rating per IEC61000-4-2, level 4 and can be used with digital applications such as USB and HDMI.



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Benefits

- Small size SESD protection diodes for high speed signals
- ESD protection in space-constrained portable electronics and mobile handsets
- Helps protect electronic circuits against damage from ESD
- Assist equipment to pass IEC61000-4-2, level 4 testing

Features

- RoHS compliant
- Halogen free (refers to: Br≤900ppm, Cl≤900ppm, Br+Cl≤1500ppm)
- Low-leakage current - 1.0μA (max)
- Low-breakdown voltage < 5.8V
- Capable of withstanding numerous ESD strikes
- Low capacitance and insertion loss
- SOD-923 case epoxy material meets UL 94 V-0
- SESD0402S devices meet MSL-1 requirements

Applications

- Mobile phones and portable electronics
- High-speed data lines (low capacitance 0201 and 0402)
- Low-voltage antenna ports (bi-directional 0201)
- USB 2.0/3.0, HDMI 1.3/1.4, and DisplayPort
- Applications requiring high ESD performance in a small package

Table SE1 Maximum Ratings for SESD Devices

Part Number	IEC61000-4-2, level 4 (ESD Withstand)		Temperature		Total Power Dissipation on FR-4 board* (mW)
	Contact (kV)	Air (kV)	Operating (°C)	Storage (°C)	
SESD0201C-006-058	±8	±15	-40 to +125	-40 to +125	150
SESD0201C-120-058	±8	±15	-40 to +125	-40 to +125	250
SESD0402S-005-054	±10	±15	-55 to +125	-55 to +150	250

*FR-4 board = 30mm x 30mm x 2mm

Table SE2 Electrical Characteristics @T=25°C for SESD Devices

Part Number	Input Capacitance*		Leakage Current (max) I_L @ $V_{WRV} = 5.0V$ (µA)	Breakdown Voltage (min) V_{br} @ $I_T^{**} = 1mA$ (V)	Working Reverse Voltage V_{WRV} @ peak (V)
	Typical (pF)	Maximum (pF)			
SESD0201C-006-058	0.6 [†]	0.9	1.0	±5.8	5.0
SESD0201C-120-058	12.0	13.5	1.0	±5.8	5.0
SESD0402S-005-054	0.5 [‡]	0.9	1.0	+5.4 / -1.0	5.0

* @ Vr=0V, f=1MHz

† 0.19pF@f=3GHz

‡ 0.17pF@f=3GHz

** V_{br} is measured at test current I_T

Figure SE1-SE2 Capacitance vs Frequency for SESD Devices

Figure SE1

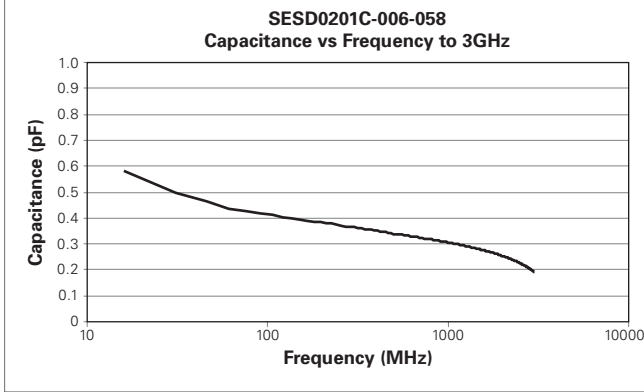


Figure SE2

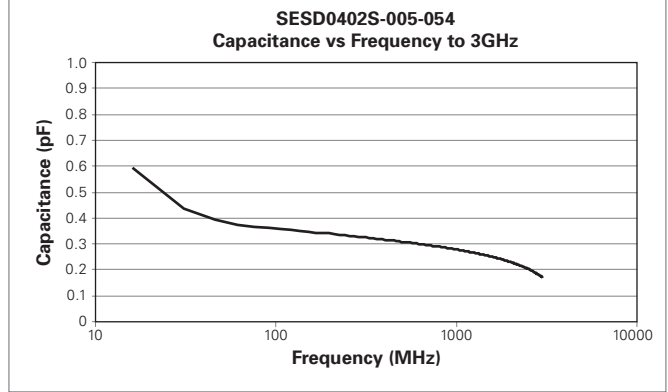
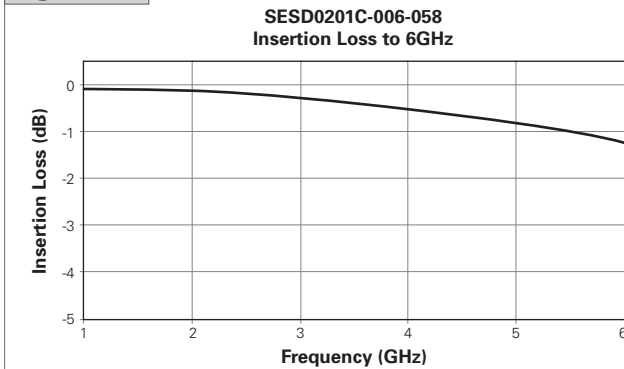


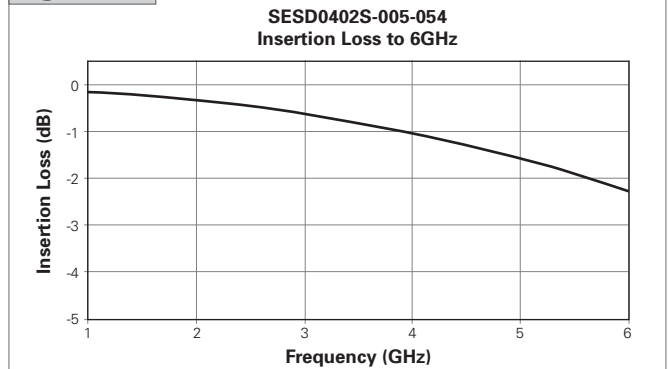
Figure SE3-SE4 Insertion Loss Diagram for SESD Devices

Figure SE3



Applications	Insertion Loss	@Frequency (GHz)
HDMI 1.3 (1080p)	-0.205	2.25
HDMI 1.3 (max spec)	-0.354	3.40
DisplayPort	-0.235	2.70
USB 3.0	-0.791	5.00

Figure SE4



Applications	Insertion Loss	@Frequency (GHz)
HDMI 1.3 (1080p)	-0.300	2.25
HDMI 1.3 (max spec)	-0.735	3.40
DisplayPort	-0.335	2.70
USB 3.0	-1.450	5.00

Table SE3 Dimensions for SESD Devices in Millimeters (Mils)*

Part Number	A	B	C	D	E	F	G	Figure
SESD0201C	0.60 ± 0.03 (23.62 ± 1.20)	0.30 ± 0.03 (11.81 ± 1.20)	0.27 ± 0.03 (10.63 ± 1.20)	0.15 ± 0.03 (5.91 ± 1.20)	0.25 ± 0.03 (9.84 ± 1.20)	0.25 ± 0.03 (9.84 ± 1.20)	0.005 (max) (0.197) (max)	SE5
SESD0402S	1.00 ± 0.05 39.37 ± 0.40	0.60 ± 0.05 23.62 ± 0.40	0.37 ± 0.03 14.57 ± 1.20	0.20 ± 0.05 7.87 ± 2.00	0.10 ± 0.05 3.94 ± 2.00	0.80 ± 0.05 31.50 ± 2.00	0.12 ± 0.05 4.72 ± 2.00	SE6

* Round off approximation

Figure SE5-SE6 Dimension Figures for SESD Devices

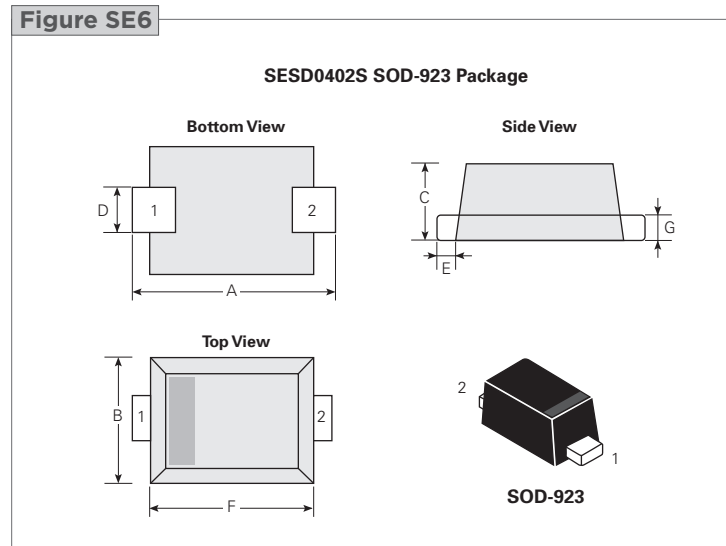
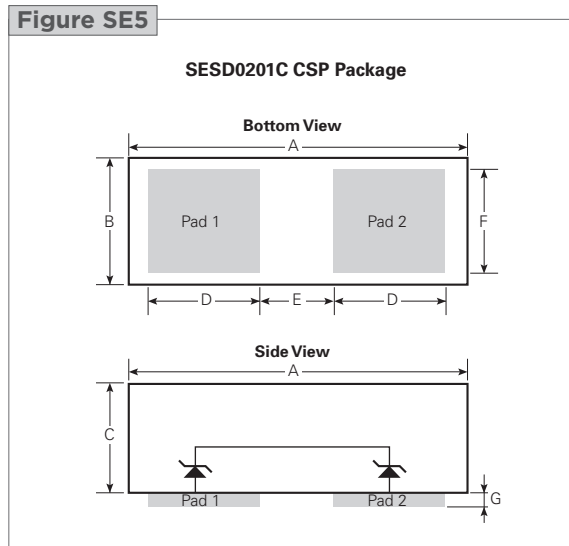


Table SE4 PCB Pad Layout for SESD Devices in Millimeters (Mils)*

Part Number	L	S	W	Figure
SESD0201C	0.28 ± 0.01 (11.0 ± 0.40)	0.19 ± 0.01 (7.50 ± 0.40)	0.30 ± 0.01 (11.80 ± 0.40)	SE7
SESD0402S	0.30 ± 0.01 (11.80 ± 0.40)	0.60 ± 0.01 (23.60 ± 0.40)	0.40 ± 0.01 (15.70 ± 0.40)	SE7

* Round off approximation

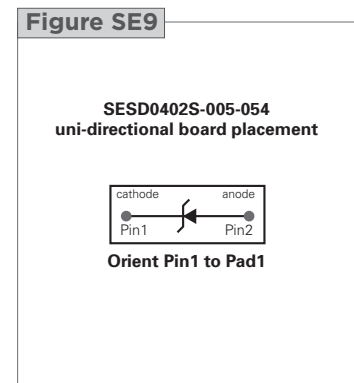
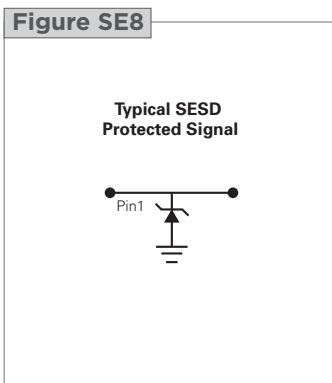
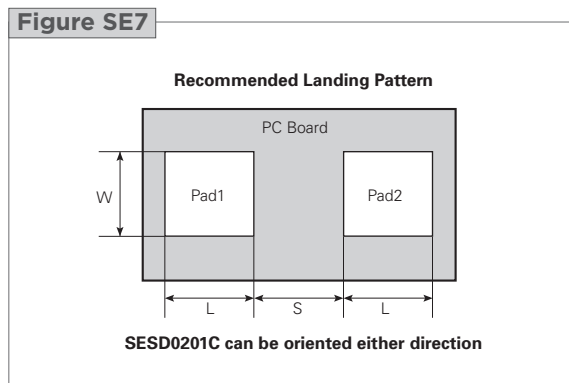


Table SE5 Tape and Reel Specifications for SESD Devices

Tape Dimension	SESD0201C-006-058	SESD0201C-120-058	SESD0402S-005-054
EIA Mark	Dimension (mm)	Dimension (mm)	Dimension (mm)
A ₀	0.37 ± 0.03	0.37 ± 0.03	0.66 ± 0.05
B ₀	0.67 ± 0.03	0.67 ± 0.03	1.06 ± 0.05
D ₀	1.60 (max)	1.60 (max)	1.60 (max)
D ₁	1.00 (min)	1.00 (min)	1.00 (min)
E ₁	1.75 ± 0.10	1.75 ± 0.10	1.75 ± 0.10
E ₂	5.85 (min)	5.85 (min)	5.85 (min)
F	3.50 ± 0.05	3.50 ± 0.05	3.50 ± 0.05
P ₀	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10
P ₁	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.05
P ₂	2.00 ± 0.10	2.00 ± 0.10	2.00 ± 0.10
W	8.00 ± 0.30	8.00 ± 0.30	8.00 ± 0.30
Tape Thickness			
EIA Mark	Dimension (mm)	Dimension (mm)	Dimension (mm)
B ₁	0.67 ± 0.03	0.67 ± 0.03	1.06 ± 0.05
K ₀	0.35 ± 0.03	0.35 ± 0.03	0.48 ± 0.05
T	0.60 (max)	0.60 (max)	0.60 (max)
T ₁	0.10 (min)	0.10 (min)	0.10 (min)
T ₂	1.05 ± 0.03	1.05 ± 0.03	1.05 ± 0.03
Reel Dimension			
EIA Mark	Dimension (mm)	Dimension (mm)	Dimension (mm)
A	178 (max)	178 (max)	178 (max)
B	1.60 (min)	1.60 (min)	1.60 (min)
C	13.0 ± 0.2	13.0 ± 0.2	13.0 ± 0.2
D	20.2 (min)	20.2 (min)	20.2 (min)
N	50.0 (min)	50.0 (min)	50.0 (min)
W ₁	9.15 ± 0.75	9.15 ± 0.75	9.15 ± 0.75
W ₂	14.4 (max)	14.4 (max)	14.4 (max)
W ₃	10.9 (max)	10.9 (max)	10.9 (max)

Figure SE10 EIA Referenced Taped Component Dimensions for SESD Devices

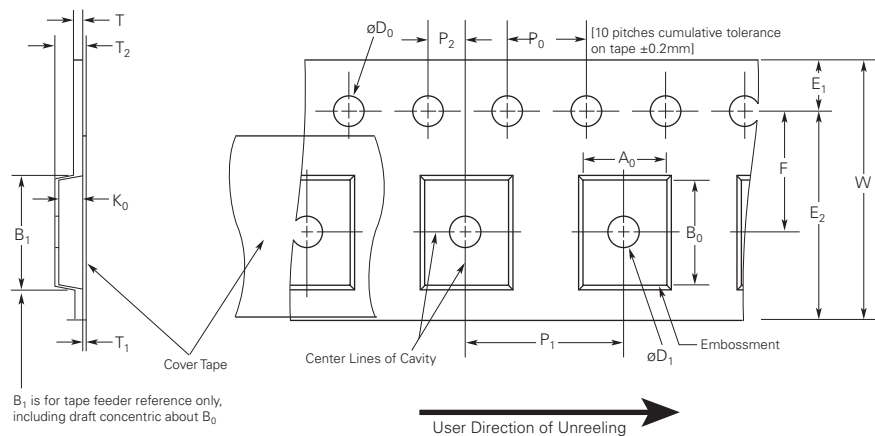
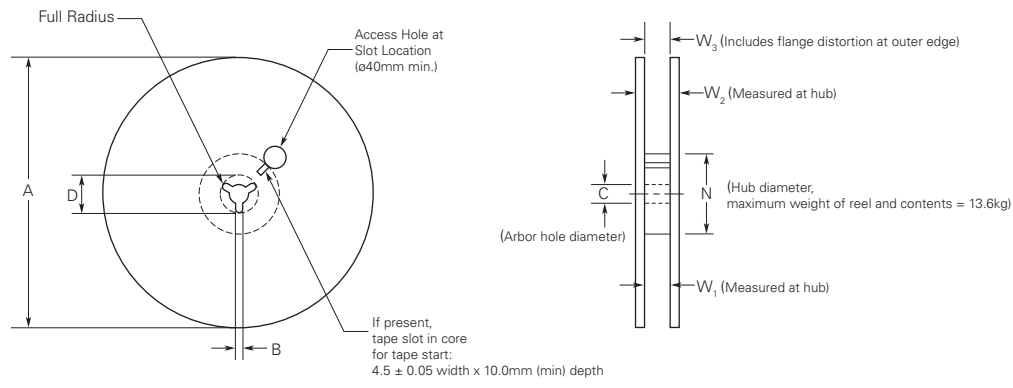


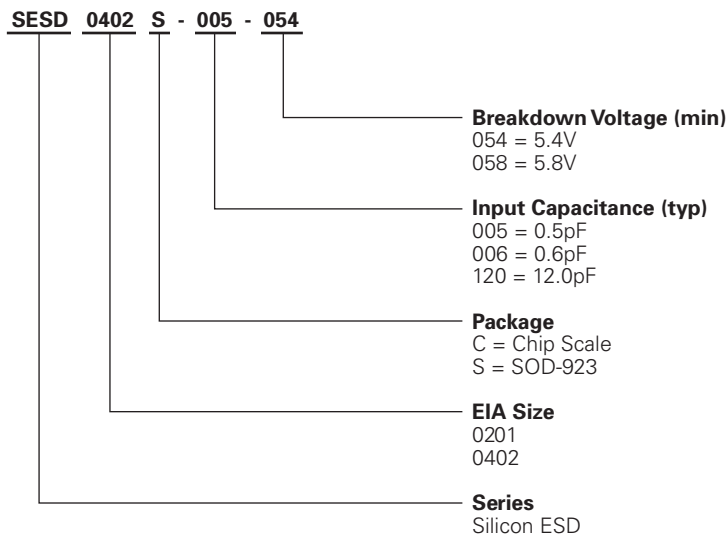
Figure SE11 EIA Referenced Reel Dimensions for SESD Devices



Definitions of Terms for SESD Devices

I_L	Reverse Leakage Current @ V_{RWM}
V_{WRV}	Working Peak Reverse Voltage
V_{br}	Breakdown Voltage @ I_T
I_T	Test Current

Part Numbering System for SESD Devices



Warning :

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